

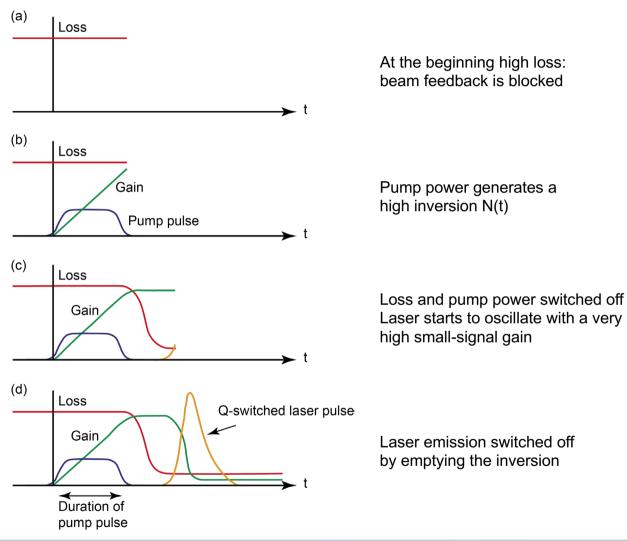
Ultrafast Laser Physics

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Chapter 6: Q-switching

Active Q-switching



Q-switching parameter range

Parameter	Range	Typical
Pulse duration	<ns many="" ns<="" td="" to=""><td>ns to tens of ns</td></ns>	ns to tens of ns
Pulse energy	μJ to many J	mJ
Pulse repetition rate	Hz to MHz	kHz
Peak power	kW to GW	hundreds of kW

 Note that many of the practical laser system examples discussed in this chapter are not typical, but rather optimized for the generation of the shortest possible pulses

Watch out: Different notation!

There is however one main difference in this chapter compared to many other chapters. All loss and gain coefficients are given for the intensity and not the amplitude and are therefore a factor of 2 larger!

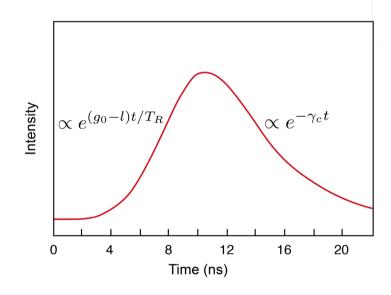
- to tal nonsaturable **intensity** loss coefficient per resonator round-trip (i.e. without the saturable absorber, but includes output coupler loss and any additional parasitic loss also the nonsaturable losses of the saturable absorber
- s a turable **intensity** loss coefficient of the saturable absorber per cavity round-trip
- q_0 unbleached **intensity** loss coefficient of the saturable absorber per cavity round-trip (i.e. maximum q at low intensity)
- s a turated **intensity** gain coefficient per resonator round-trip (please note here we use intensity gain and not amplitude gain)
- g_0 **intensity** small signal gain coefficient per resonator round-trip (often also simply called small signal gain). For a homogenous gain material applies in steady-state (factor 2 for a linear standing-wave resonator):

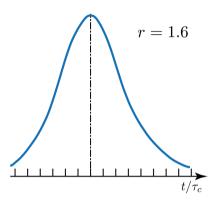
$$g = \frac{g_0}{1 + 2I/I_{sat}}$$

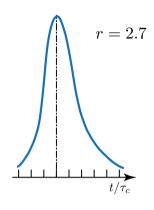
Pulse shape and pulse duration

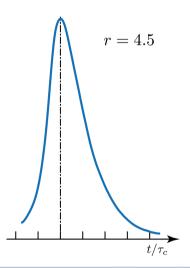
$$g_0 = rl$$

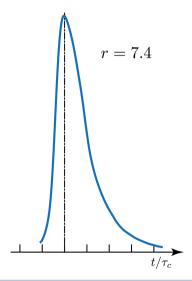
$$g_0 = rl \qquad \qquad \gamma_c = l/T_R$$



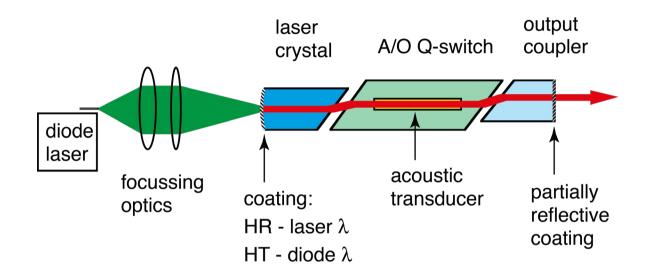








ETHzürich AOM Q-switched diode-pumped ss-laser

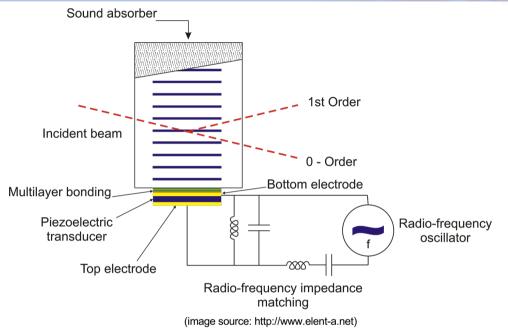


Nd:YLF: 700 ps, 1 kHz, P_{peak} = 15 kW, P_{av} = 10.5 mW, E_p = 10.5 μ J

Nd:YVO₄: 600 ps, 1 kHz, P_{peak} = 5 kW, P_{av} = 3 mW, E_p = 3 μ J

H. Plaessmann et al., Appl. Opt. 32, 6616 (1993)

ETHzürich How an acousto-optic modulator works

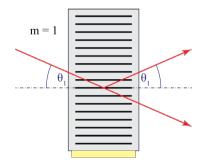


- Acoustic carrier frequency: about 10 MHz – 2 GHz
- Wavelength of acoustic wave:

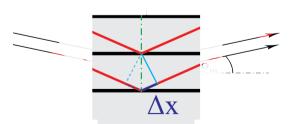
$$\Lambda = \frac{c_{\text{sound}}}{f_{\text{acoustic}}}$$

 Diffraction angle determined by Bragg condition:

$$\sin(\theta_m) = \frac{m\lambda}{2n\Lambda}$$



- When acoustic wave is present: high losses due to diffraction into 1st order
- Switch acoustic wave on and off at desired Q-switched pulse repetition rate ($f_{rep} << f_{acoustic}$)



$$k_n \cdot 2\Delta x \stackrel{!}{=} m \cdot 2\pi$$

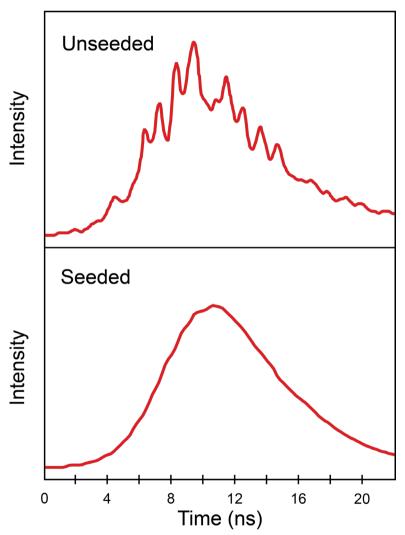
$$k_n \cdot 2\Lambda \cos(90^{\circ} - \theta_m) \stackrel{!}{=} m \cdot 2\pi$$

$$\sin(\theta_m) \stackrel{!}{=} \frac{m\lambda}{2n\Lambda}$$

Seeded Q-switched laser

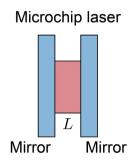
Ideally a Q-switched laser is a single axial mode laser.

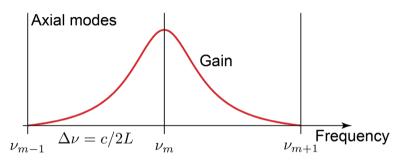
Seeding with a low-power single mode laser.



Single mode operation

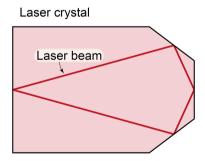
• Microchip laser cavity length small: axial mode spacing larger than gain bandwidth



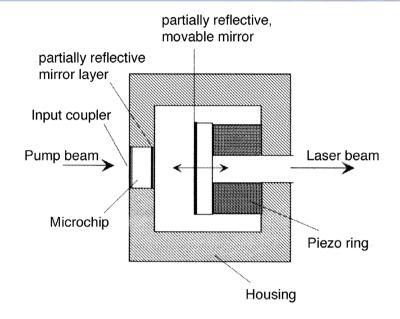


Unidirectional ring laser

no spatial hole burning: no standing wave example: MISER or NPRO (nonplanar ring oscillator). Applied magnetic field forces unidirectional operation (Faraday effect).



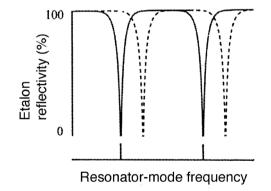
Actively Q-switched microchip laser



Tunable etalon (i.e. Fabry-Perot)

Active Q-switching by shifting the Fabry-Perot resonance frequency in and out of the microchip axial mode.

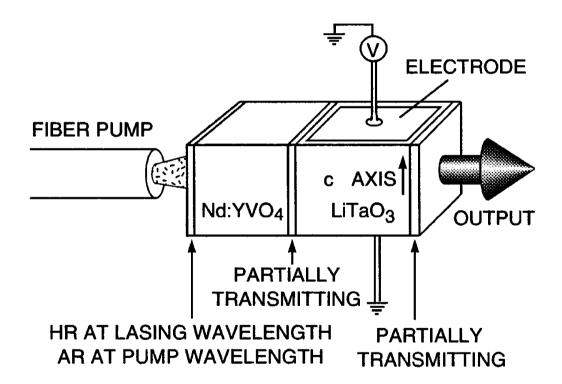
Etalon resonance shifted with a movable mirror.



J. J. Zayhowski et al., IEEE J. Quantum Electronics 27, 2220 (1991)

Actively Q-switched microchip laser

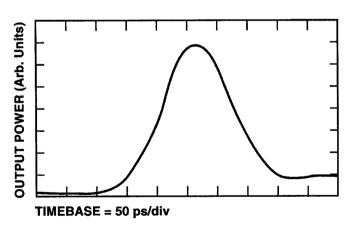
J. J. Zayhowski et al., *Opt. Lett.* **20**, 716 (1995)



Tunable etalon (i.e. Fabry-Perot)

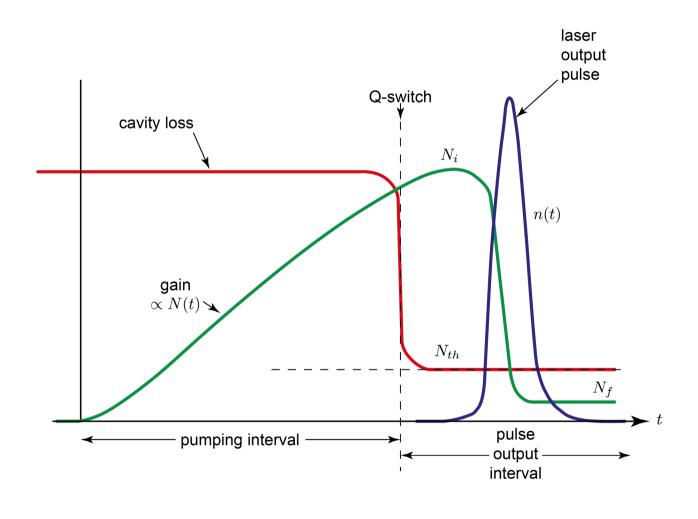
Active Q-switching by shifting the Fabry-Perot resonance frequency in and out of the microchip axial mode.

Etalon resonance shifted with an electrooptical effect.



115 ps, 1 kHz shortest pulses with active Q-switching

Theory for active Q-switching

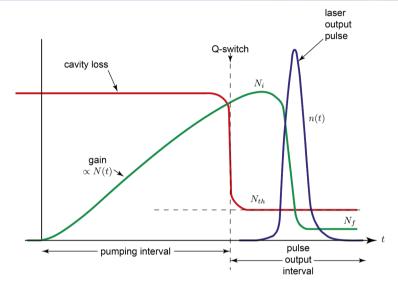


$$\frac{dn}{dt} = KNn - \gamma_c n$$

$$\frac{dN}{dt} = R_p - \gamma_L N - KNn$$

$$R_p = \frac{P_{abs}}{h\nu_{pump}}$$

ETHzürich Theory for active Q-switching: build-up phase



$$\frac{dn}{dt} = KNn - \gamma_c n$$

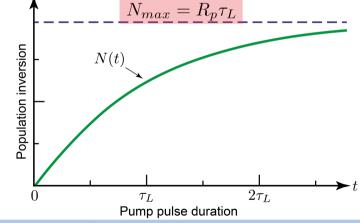
$$\frac{dN}{dt} = R_p - \gamma_L N - KNn$$

Build-up phase: loss high and lasing threshold not reached: $n(t) \approx 0$, $R_p = \mathrm{const.}$

It needs $\approx 3\tau_L$ to reach maximum inversion.

$$\frac{dN}{dt} \approx R_p - \gamma_L N = R_p - \frac{N}{\tau_L}$$

$$N(t) = R_p \tau_L \left[1 - \exp\left(-t/\tau_L\right) \right]$$
$$= N_{max} \left[1 - \exp\left(-t/\tau_L\right) \right]$$



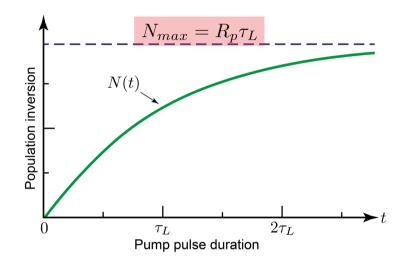
ETHzürich Theory for active Q-switching: build-up phase

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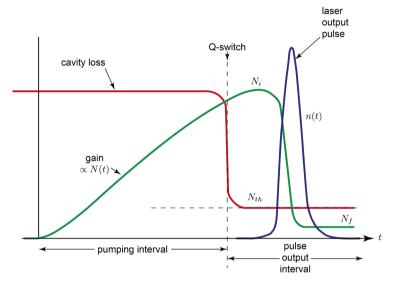
$$N(t) = R_p \tau_L \left[1 - \exp\left(-t/\tau_L\right) \right]$$
$$= N_{max} \left[1 - \exp\left(-t/\tau_L\right) \right]$$



$$E_p = \text{const.} \iff T_{rep} > \approx 3\tau_L, \text{ or } f_{rep} = \frac{1}{T_{rep}} < \approx \frac{1}{3\tau_L}$$

Example: Nd:YLF, upper state lifetime 480 μ s, $\frac{1}{3 au_L}=$ 0.7 kHz

ETHzür/Theory for active Q-switching: leading edge of pulse



$$\frac{dn}{dt} = KNn - \gamma_c n$$

$$\frac{dN}{dt} = R_p - \gamma_L N - KNn$$

$$N(t=0) = N_i$$

1. Approximation: t = 0 losses are instantaneously switched off $n(t = 0) = n_i \approx 1$

$$n(t=0)=n_i\approx 1$$

2. Approximation: inversion not reduced during early build-up phase

$$N(t) \approx N_i \approx \text{const.}$$

$$\frac{dn}{dt} \approx K(N_i - N_{th})n = KN_{th}(r - 1)n = \frac{r - 1}{\tau_c}n$$

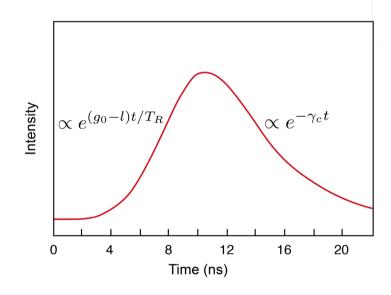
$$r = N_i/N_{th}$$

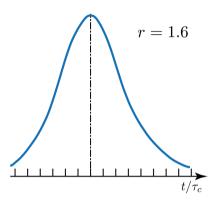
$$n(t) \approx n_i \exp\left(\frac{r-1}{\tau_c}t\right) \xrightarrow{\tau_c = T_R/l, \ g_0 = rl} = n_i \exp\left[(g_0 - l)\frac{t}{T_R}\right]$$

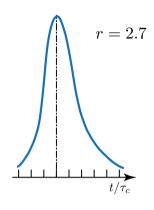
Pulse shape and pulse duration

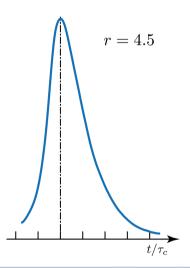
$$g_0 = rl$$

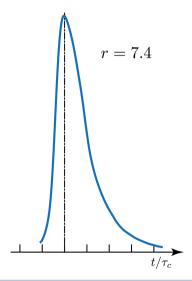
$$g_0 = rl \qquad \qquad \gamma_c = l/T_R$$



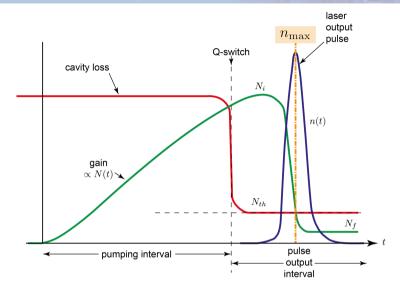








End züri Theory for active Q-switching: during pulse duration



$$\frac{dn}{dt} = KNn - \gamma_c n \qquad \qquad N_{th} = \gamma_c / K$$

$$N_{th} = \gamma_c / K$$

$$\frac{dN}{dt} = R_p - \gamma_L N - KNn$$

$$\frac{dn}{dN} \approx \frac{K(N - N_{th})n}{-KnN} = \frac{N_{th} - N}{N}$$

$$\frac{dn}{dt} = K(N - N_{th})n$$

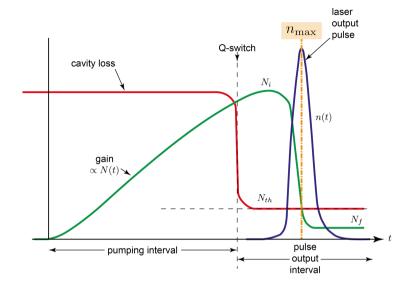
$$\frac{dN}{dt} \approx -KnN$$

$$dn \approx \frac{N_{th} - N}{N} dN \xrightarrow{N(t=0) = N_i = rN_{th}, \ n(t=0) = n_i \approx 1} \int_{n_i}^{n(t)} dn \approx \int_{N_i = rN_{th}}^{N(t)} \frac{N_{th} - N}{N} dN$$

$$n(t) \approx N_i - N(t) - \frac{N_i}{r} \ln \left(\frac{N_i}{N(t)} \right), \text{ with } N_i = rN_{th}$$
 $n(t) = n_{\text{max}} \text{ for } g = l \iff N(t) = N_{th}$

$$n(t) = n_{\text{max}} \text{ for } g = l \iff N(t) = N_{th}$$

ETHzüriTheory for active Q-switching: during pulse duration

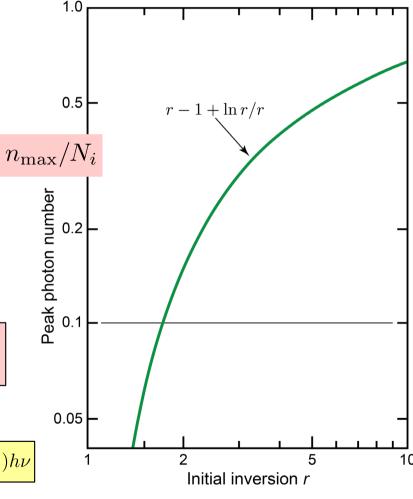


$$n(t) = n_{\text{max}} \text{ for } g = l \iff N(t) = N_{th}$$

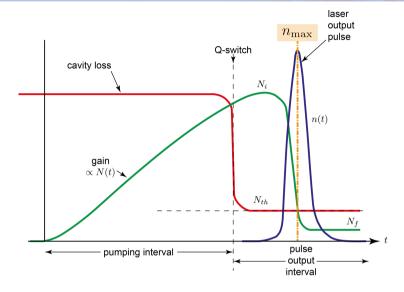
$$n_{\text{max}} \approx \frac{r - 1 - \ln r}{r} N_i$$
, with $N_i = r N_{th}$

$$P_{\rm p,out} = \frac{n_{\rm max}h\nu}{\tau_c}$$

$$E_{\rm p,out} \approx E_p \approx (N_i - N_f) h \nu$$



ETHzüriTheory for active Q-switching: during pulse duration



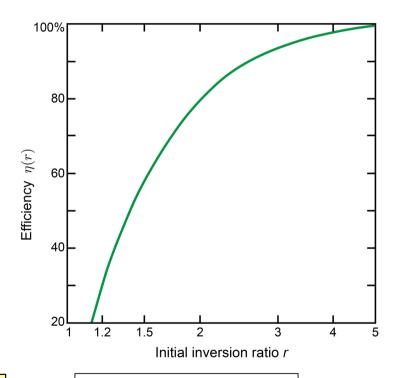
$$n(t) = n_{\text{max}} \text{ for } g = l \iff N(t) = N_{th}$$

$$n_{\max} \approx \frac{r - 1 - \ln r}{r} N_i$$
, with $N_i = r N_{th}$

$$P_{\rm p,out} = \frac{n_{\rm max}h\nu}{\tau_c}$$

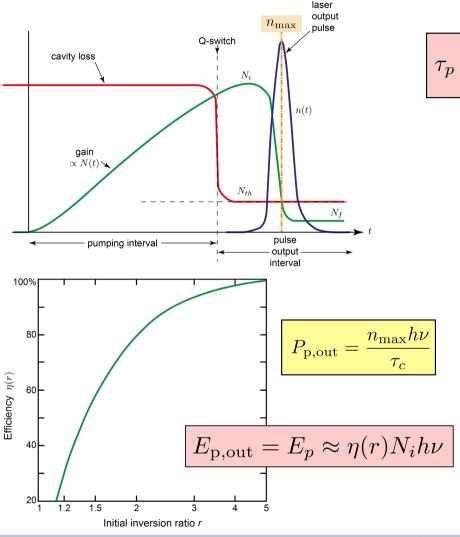
$$E_{\rm p,out} \approx E_p \approx (N_i - N_f) h \nu$$

$$\eta \equiv \frac{\text{Q-switched pulse energy}}{\text{stored energy}} = \frac{(N_i - N_f)h\nu}{N_i h\nu} = \frac{N_i - N_f}{N_i}$$

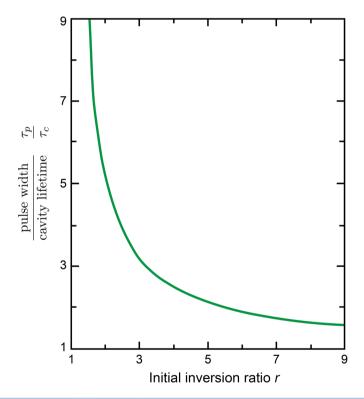


$$E_{\rm p,out} = E_p \approx \eta(r) N_i h \nu$$

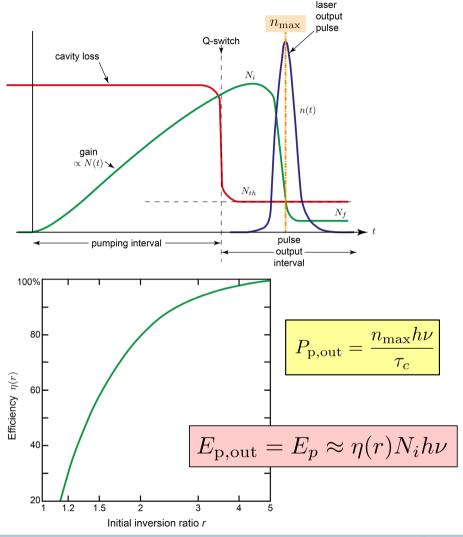
ETHzüriTheory for active Q-switching: during pulse duration



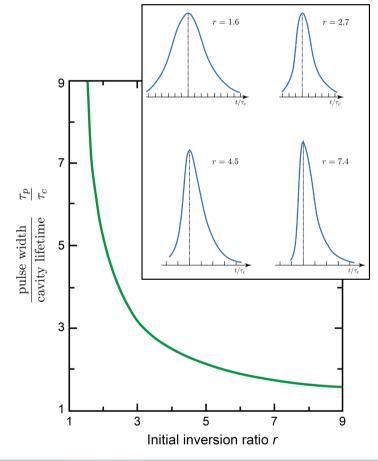
$$au_p pprox rac{E_{
m p,out}}{P_{
m p,out}} pprox rac{\eta(r)N_i}{n_{
m max}} au_c pprox rac{r\eta(r)}{r - 1 - \ln r} au_c$$



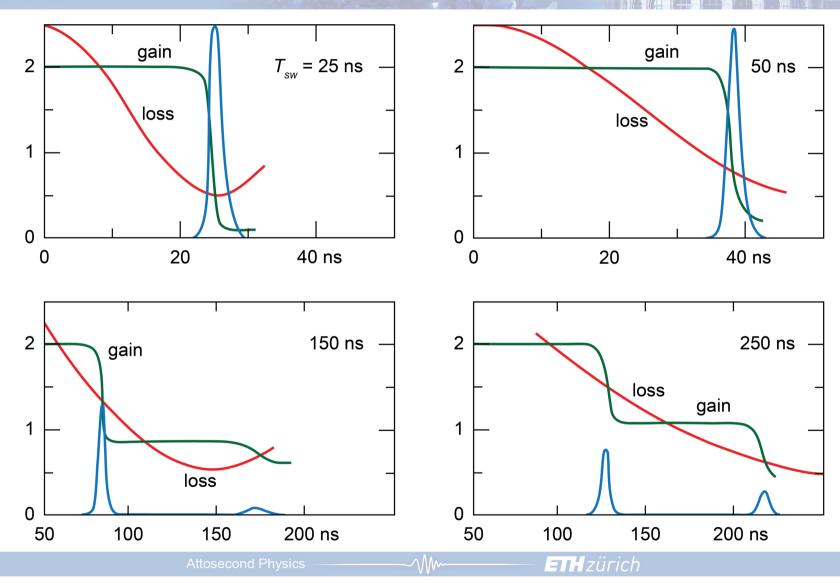
ETHzuriTheory for active Q-switching: trailing edge of pulse



$$n(t) = n_{\text{max}} \exp(-t/\tau_c)$$

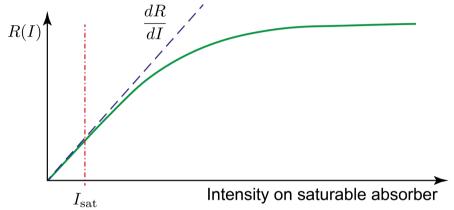


Effects of a slow Q-switch



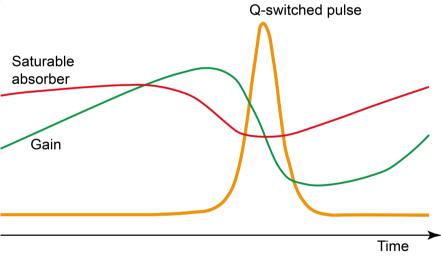
Passive Q-switching

Saturable absorber integrated into a mirror (saturable reflector)



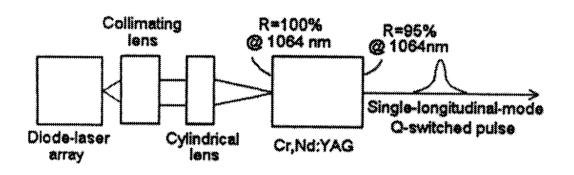
Condition for Q-switching

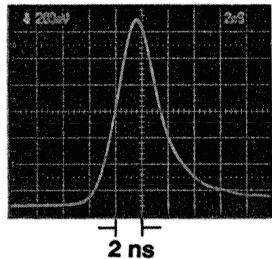
$$\left| \frac{dR}{dI} \right| I > \frac{T_R}{\tau_{\text{stim}}} \approx r \frac{T_R}{\tau_L}$$



F. X. Kärtner, L. R. Brovelli, D. Kopf, M. Kamp, I. Calasso, and U. Keller, Opt. Eng. 34, 2024 (1995)

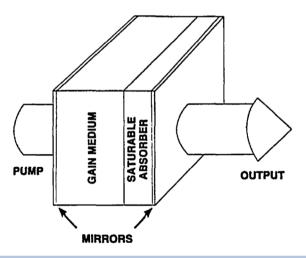
Passively Q-switched microchip laser





290 ps, 8 µJ

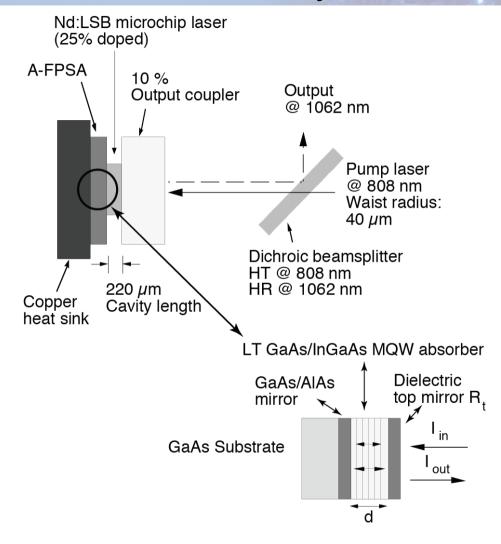
P. Wang et al, Opt. Commun. 114, 439 (1995)

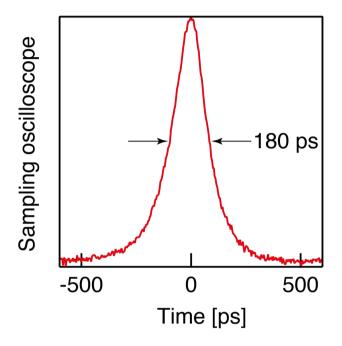


 $337 \text{ ps}, 11 \mu\text{J}, 6 \text{ kHz}$

J. J. Zayhowski et al., Opt. Lett. 19, 1427 (1994)

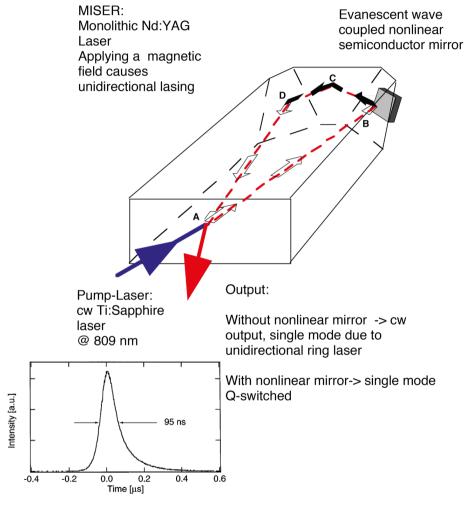
Passively Q-switched microchip laser



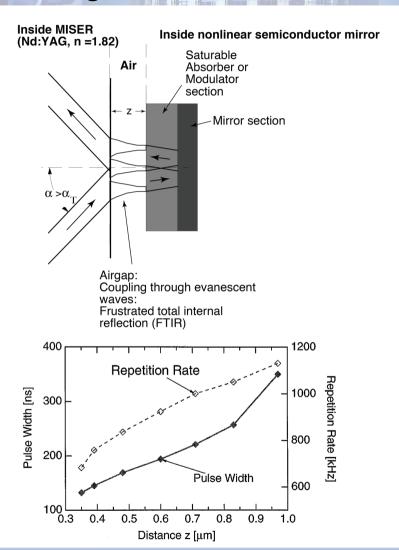


B. Braun et al., Opt. Lett. 21, 405 (1996)

Passively Q-switched ring laser



B. Braun et al., Opt. Lett. 20, 1020 (1995)



TH zürich



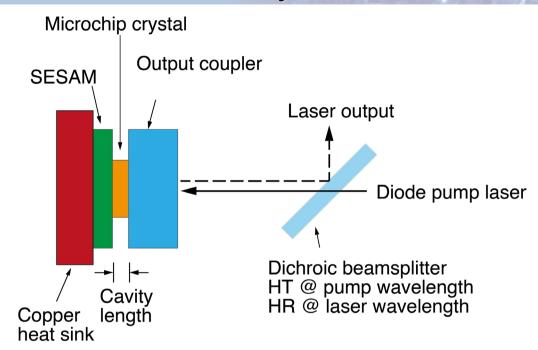
Passively Q-switched Microchip Laser

 μ J-pulses with \approx 10 kHz repetition rates $\Rightarrow \approx$ 10 mW average powers

G. J. Spühler, R. Paschotta, R. Fluck, B. Braun, M. Moser, G. Zhang, E. Gini, and U. Keller, "Experimentally confirmed design guidelines for passively Q-switched microchip lasers using semiconductor saturable absorbers,"

J. Opt. Soc. Am. B 16, 376-388 (1999)

Passively Q-switched Microchip Laser



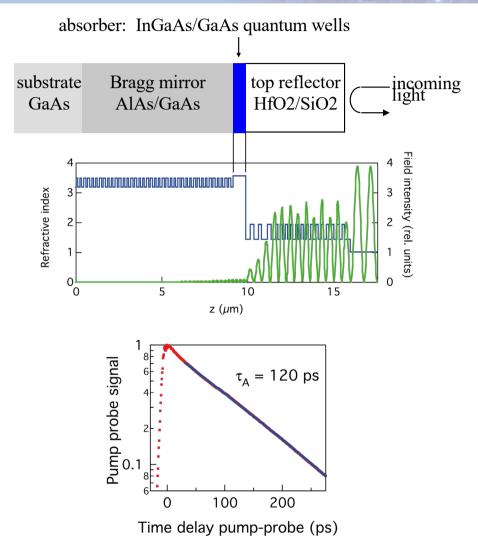
Flat/flat resonator

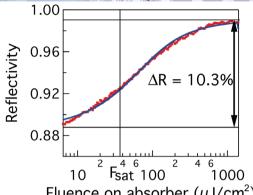
Cavity stabilization by

- Thermal lensing
- Thermal expansion
- Gain guiding

- Compact and simple all-solid-state laser
- Short cavity ⇒ Single longitudinal mode Short Q-switched pulses
- High pulse energies possible
- Good beam quality

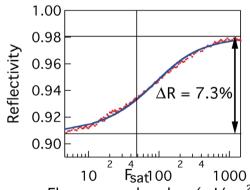
FIHzür SEmiconductor Saturable Absorber Mirror (SESAM)





Fluence on absorber (μ J/cm²)

SESAM #1: $\Delta R = 10.3\%$ $F_{\rm sat} = 36 \ \mu \text{J/cm}^2$



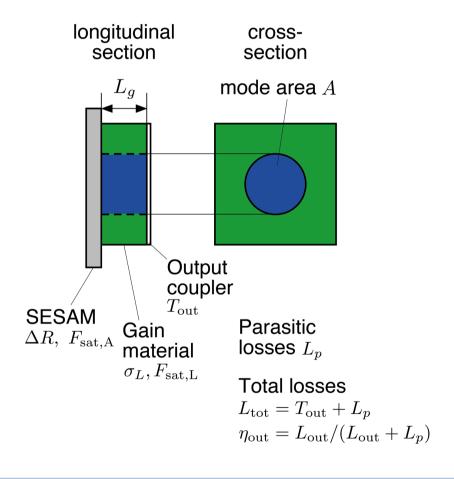
Fluence on absorber (μ J/cm²)

SESAM #2:
$$\Delta R = 7.3\%$$

$$F_{\rm sat} = 47 \ \mu \text{J/cm}^2$$

Model

Cavity setup



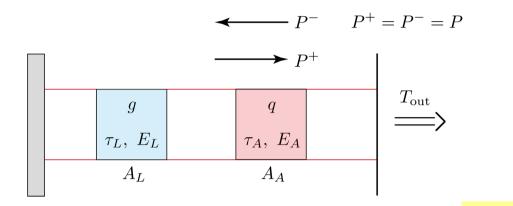
Assumptions

- No spatial hole burning
- No beam divergence in cavity
- Small changes per round-trip of gain, loss, and power

•
$$F_{\rm sat,A} \ll F_{\rm sat,L} = \frac{h\nu_L}{2\sigma_L}$$

- SESAM always F_{sat,A} << F_{sat,L}
- Cr:YAG/Nd:YAG Systems:
 F_{sat A} ≈ F_{sat I}
- $\tau_A > \tau_p$

Theory for passive Q-switching



$$n = \frac{P}{h\nu} T_R \xrightarrow{T_R = 2L/c} = \frac{2L}{ch\nu} P$$

$$g = L_g \frac{N_L}{V} \sigma_L \xrightarrow{V = A_L L_g} = \frac{N_L}{A_L} \sigma_L \qquad q = \frac{N_A}{A_A} \sigma_A$$

$$W^{\text{stim}} = K_L n = \frac{I}{h\nu} \sigma_L = \frac{P}{A_L h\nu} \sigma_L \qquad K_L = \frac{\sigma_L}{A_L T_R}$$

$$\frac{dn}{dt} = \left(K_L N_L - K_A N_A - \frac{1}{\tau_c}\right) n$$

$$\frac{dN_L}{dt} = -\frac{N_L}{\tau_L} - K_L n N_L + R_p$$

$$\frac{dN_A}{dt} = -\frac{N_A - N_{A0}}{\tau_A} - K_A n N_A$$

$$T_R \frac{dP(t)}{dT} = [g(t) - l(t) - q(t)] P(t)$$

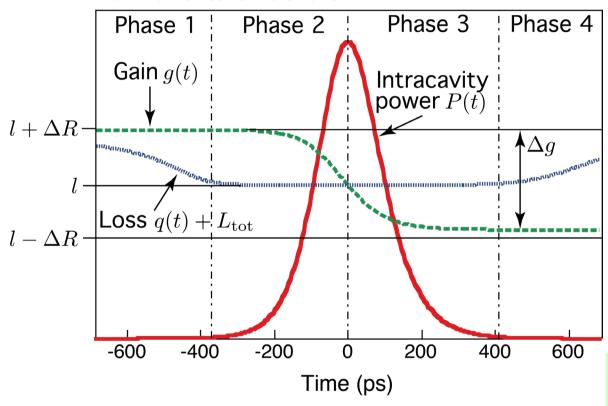
$$\frac{dg(t)}{dt} = -\frac{g(t) - g_0}{\tau_L} - \frac{g(t)P(t)}{E_L}$$

$$\frac{dq(t)}{dt} = -\frac{q(t) - q_0}{\tau_A} - \frac{q(t)P(t)}{E_A}$$

Neglect spontaneous emission into laser mode

Q-switched pulse

from numerical simulations



stored energy:

$$E_{\text{stored}} = E_L g$$

released energy: E_L saturation energy of the laser

$$E_{\text{released}} = E_L \Delta g$$

l: total nonsaturable loss

 l_p : parasitic loss

 q_0 : saturable loss

$$q_0 \approx \Delta R$$

from rate equations:

optimum pulse energy if (if $l_p \neq 0$):

$$T_{\rm out} + L_p \approx \Delta R$$

gain reduction: (for $L_{\text{tot}} \ge \Delta R$):

$$\Delta g \approx 2\Delta R$$

Q-switched pulse

Phase 1:

- absorber unbleached
- power grows when gain reaches loss
 E_A << E_L ⇒ absorber is saturated before power grows significantly

Phase 2:

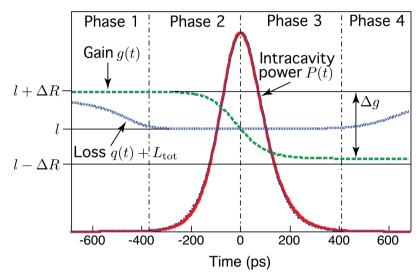
- absorber fully bleached
- power grows quickly until gain is depleted to the loss level

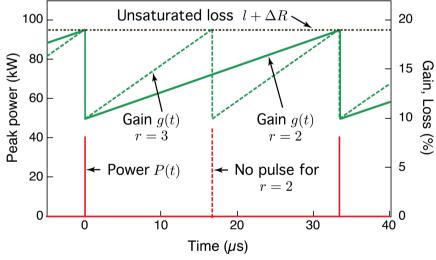
Phase 3:

- power decays
- energy is still extracted, and gain decays further

Phase 4:

- absorber recovers more quickly than gain
- next Phase 1 starts when gain reaches the unsaturated losses





Model

Pulse energy#:

$$E_p \approx \frac{h\nu_L}{\sigma_L} A\Delta R \eta_{\rm out}$$

 $\Rightarrow E_p/A$ independent of pump power

Pulse duration*#:

$$au_p pprox rac{3.52T_R}{\Delta R}$$

⇒ independent of pump power

Repetition rate#:

$$f_{\rm rep} pprox rac{g_0 - (L_{
m tot} + \Delta R)}{2\Delta R au_L}$$

pumping harder \Rightarrow more pulses of same width, shape and fluence three-level lasers: replace σ_L by $\sigma_L + \sigma_L^{abs}$

^{*}Spühler et al., JOSA B 16, 376-388 (1999)

^{*}Zayhowski et al. *IEEE J. Quantum Electron*. 27, 2220-2225 (1991)

Design guidelines: Short pulses

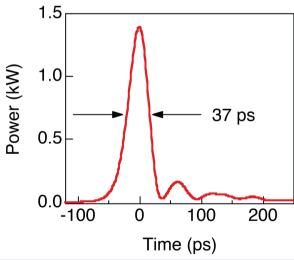
- short cavity (T_R)
- large modulation depth ΔR
- large gain cross-section σ_L

$$au_p pprox rac{3.52T_R}{\Delta R}$$

⇒ Nd:YVO₄: small absorption length, high gain

Spühler et al., JOSA B 16, 376-388 (1999)

45 GHz sampling oscilloscope trace



shortest Q-switched pulses from a solid state laser

185 µm Nd:YVO₄

$$P_{\text{pump}} = 460 \text{ mW}$$
 $f_{\text{rep}} = 160 \text{ kHz}$
 $E_{\text{p}} = 53 \text{ nJ}$
 $\Delta R \approx 13\%$

so far τ_p limited by available ΔR and available crystal thickness, not by gain